HALOGEN

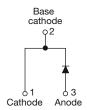
**FREE** 



# Vishay Semiconductors

# Hyperfast Rectifier, 8 A FRED Pt®

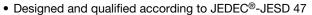




PRIMARY CHARACTERISTICS									
I <sub>F(AV)</sub>	8 A								
V <sub>R</sub>	600 V								
V <sub>F</sub> at I <sub>F</sub>	1.3 V								
t <sub>rr</sub> typ.	18 ns								
T <sub>J</sub> max.	175 °C								
Package	2L TO-220AC								
Circuit configuration	Single								

#### **FEATURES**

- Hyperfast recovery time
- Low forward voltage drop
- 175 °C operating junction temperature
- Low leakage current



 Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

### **DESCRIPTION / APPLICATIONS**

State of the art hyperfast recovery rectifiers designed with optimized performance of forward voltage drop, hyperfast recovery time, and soft recovery.

The planar structure and the platinum doped life time control guarantee the best overall performance, ruggedness and reliability characteristics.

These devices are intended for use in PFC boost stage in the AC/DC section of SMPS, inverters or as freewheeling diodes.

Their extremely optimized stored charge and low recovery current minimize the switching losses and reduce over dissipation in the switching element and snubbers.

ABSOLUTE MAXIMUM RATINGS										
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS						
Repetitive peak reverse voltage	$V_{RRM}$		600	V						
Average rectified forward current	I <sub>F(AV)</sub>	T <sub>C</sub> = 144 °C	8							
Non-repetitive peak surge current	I <sub>FSM</sub>	T <sub>J</sub> = 25 °C	90	Α						
Repetitive peak forward current	I <sub>FM</sub>		16							
Operating junction and storage temperatures	T <sub>J</sub> , T <sub>Stg</sub>		-65 to +175	°C						

<b>ELECTRICAL SPECIFICATIONS</b> (T <sub>J</sub> = 25 °C unless otherwise specified)										
PARAMETER	SYMBOL	SYMBOL TEST CONDITIONS			MAX.	UNITS				
Breakdown voltage, blocking voltage	$V_{BR}$ , $V_{R}$	I <sub>R</sub> = 100 μA	600	-	-	,,				
Forward voltage	V <sub>F</sub>	I <sub>F</sub> = 8 A	-	2.0	2.4	V				
		I <sub>F</sub> = 8 A, T <sub>J</sub> = 150 °C	-	1.3	1.8					
Reverse leakage current		$V_R = V_R$ rated	-	0.3	50					
neverse leakage current	I <sub>R</sub>	$T_J = 150$ °C, $V_R = V_R$ rated	= 150 °C, V <sub>R</sub> = V <sub>R</sub> rated - 55		500	- μΑ				
Junction capacitance	C <sub>T</sub>	V <sub>R</sub> = 600 V	-	17	-	pF				
Series inductance	L <sub>S</sub>	Measured lead to lead 5 mm from package body	ı	8.0	-	nΗ				



<b>DYNAMIC RECOVERY CHARACTERISTICS</b> (T <sub>C</sub> = 25 °C unless otherwise specified)									
PARAMETER	SYMBOL	TEST	CONDITIONS	MIN.	TYP.	MAX.	UNITS		
		$I_F = 1 A, dI_F/dt = 100$	I <sub>F</sub> = 1 A, dI <sub>F</sub> /dt = 100 A/μs, V <sub>R</sub> = 30 V			22			
Reverse recovery time	+	$I_F = 8 \text{ A}, dI_F/dt = 100$	-	20	25	ne			
neverse recovery time	t <sub>rr</sub>	T <sub>J</sub> = 25 °C		-	25	-	ns		
		T <sub>J</sub> = 125 °C	]	-	40	=.			
Peak recovery current	I <sub>RRM</sub>	T <sub>J</sub> = 25 °C	I <sub>F</sub> = 8 A dI <sub>F</sub> /dt = 200 A/µs	-	2.4	=.	Α		
		T <sub>J</sub> = 125 °C	V <sub>R</sub> = 390 V	-	4.8	-	^		
Poverse receivery charge	Q <sub>rr</sub>	T <sub>J</sub> = 25 °C	VR - 000 V	-	25	-	nC		
Reverse recovery charge		T <sub>J</sub> = 125 °C		-	120	=.	IIC		
Reverse recovery time	t <sub>rr</sub>		I <sub>F</sub> = 8 A	-	33	-	ns		
Peak recovery current	I <sub>RRM</sub>	T <sub>J</sub> = 125 °C	$dI_F/dt = 600 A/\mu s$	-	12	-	Α		
Reverse recovery charge	Q <sub>rr</sub>		V <sub>R</sub> = 390 V	-	220	=	nC		

THERMAL - MECHANICAL SPECIFICATIONS									
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS			
Maximum junction and storage temperature range			-65	-	175	°C			
Thermal resistance, junction-to-case	R <sub>thJC</sub>		-	1.4	2	°C/W			
Thermal resistance, junction-to-ambient per leg	R <sub>thJA</sub>	Typical socket mount	-	-	70				
Thermal resistance, case-to-heatsink	R <sub>thCS</sub>	Mounting surface, flat, smooth, and greased	-	0.5	-				
Weight			-	2.0	-	g			
weignt			-	0.07	=.	oz.			
Mounting torque			6.0 (5.0)	-	12 (10)	kgf · cm (lbf · in)			
Marking device		Case style 2L TO-220AC	8ETH06						

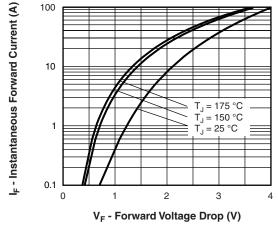


Fig. 1 - Typical Forward Voltage Drop Characteristics

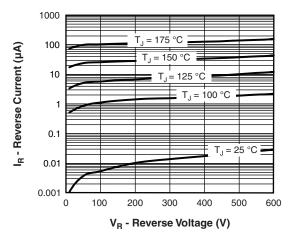


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

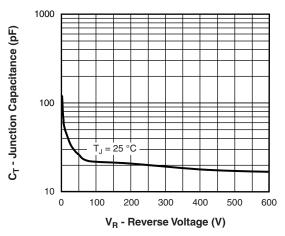


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

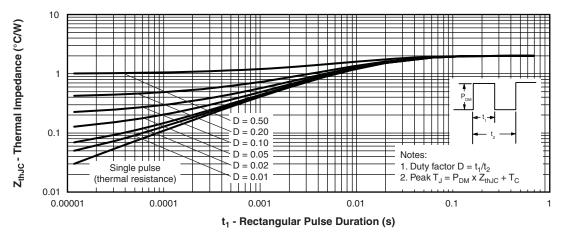
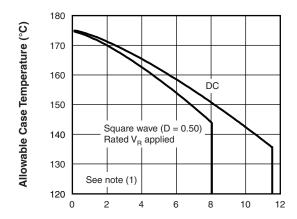


Fig. 4 - Maximum Thermal Impedance  $Z_{thJC}$  Characteristics



I<sub>F(AV)</sub> - Average Forward Current (A)
Fig. 5 - Maximum Allowable Case Temperature vs.
Average Forward Current

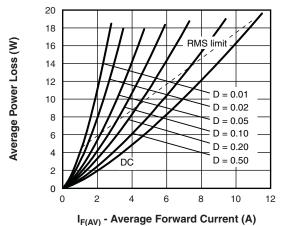


Fig. 6 - Forward Power Loss Characteristics

#### Note

 $\begin{array}{ll} \text{(1)} & \text{Formula used: } T_{\text{C}} = T_{\text{J}} - (\text{Pd} + \text{Pd}_{\text{REV}}) \times R_{\text{thJC}}; \\ \text{Pd} = \text{forward power loss} = I_{\text{F(AV)}} \times V_{\text{FM}} \text{ at } (I_{\text{F(AV)}}/D) \text{ (see fig. 5)}; \\ \text{Pd}_{\text{REV}} = \text{inverse power loss} = V_{\text{R1}} \times I_{\text{R}} \text{ (1 - D)}; I_{\text{R}} \text{ at } V_{\text{R1}} = \text{rated } V_{\text{R}} \\ \end{array}$ 



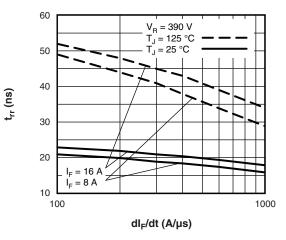


Fig. 7 - Typical Reverse Recovery Time vs. dl<sub>F</sub>/dt

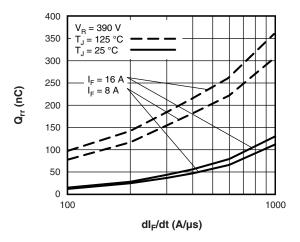
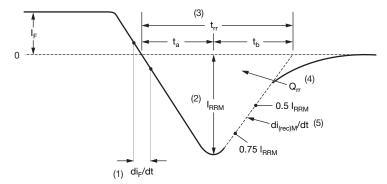


Fig. 8 - Typical Stored Charge vs. dl<sub>F</sub>/dt



- (1) di<sub>F</sub>/dt rate of change of current through zero crossing
- (2)  $I_{RRM}$  peak reverse recovery current
- (3)  $\rm t_{rr}$  reverse recovery time measured from zero crossing point of negative going  $\rm I_F$  to point where a line passing through 0.75  $\rm I_{RRM}$  and 0.50  $\rm I_{RRM}$  extrapolated to zero current.
- (4)  $\mathbf{Q}_{rr}$  area under curve defined by  $\mathbf{t}_{rr}$  and  $\mathbf{I}_{RRM}$

$$Q_{rr} = \frac{t_{rr} \times I_{RRM}}{2}$$

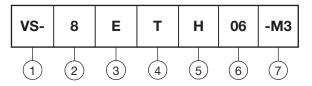
(5) di<sub>(rec)M</sub>/dt - peak rate of change of current during t<sub>b</sub> portion of t<sub>rr</sub>

Fig. 9 - Reverse Recovery Waveform and Definitions



#### **ORDERING INFORMATION TABLE**

#### Device code



- 1 Vishay Semiconductors product
- Current rating (8 = 8 A)
- E = single
- 4 T = TO-220,  $D^2PAK$  (TO-263AB)
- 5 H = hyperfast recovery
- 6 Voltage rating (06 = 600 V)
- 7 Environmental digit:
  - -M3 = halogen-free, RoHS-compliant, and termination lead (Pb)-free

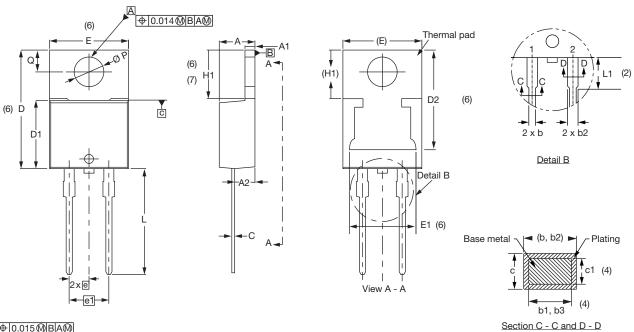
ORDERING INFORMATION (Example)									
PREFERRED P/N	QUANTITY PER T/R	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION						
VS-8ETH06-M3	50	1000	Antistatic plastic tube						

LINKS TO RELATED DOCUMENTS							
Dimensions <u>www.vishay.com/doc?96156</u>							
Part marking information	www.vishay.com/doc?95391						

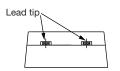


### 2L TO-220AC

#### **DIMENSIONS** in millimeters and inches



**⊕** 0.015 **M** B A **M** 



Conforms to JEDEC® outline TO-220AC

SYMBOL	MILLIMETERS		INC	HES	NOTES	NOTES	SYMBOL	MILLIN	IETERS	INC	HES	NOTES
STMBOL	MIN.	MAX.	MIN.	MAX.	NOTES		STIVIBOL	MIN.	MAX.	MIN.	MAX.	NOTES
Α	4.25	4.65	0.167	0.183			D2	11.68	12.88	0.460	0.507	6
A1	1.14	1.40	0.045	0.055			Е	10.11	10.51	0.398	0.414	3, 6
A2	2.50	2.92	0.098	0.115			E1	6.86	8.89	0.270	0.350	6
b	0.69	1.01	0.027	0.040			е	2.41	2.67	0.095	0.105	
b1	0.38	0.97	0.015	0.038	4		e1	4.88	5.28	0.192	0.208	
b2	1.20	1.73	0.047	0.068			H1	6.09	6.48	0.240	0.255	6, 7
b3	1.14	1.73	0.045	0.068	4		L	13.52	14.02	0.532	0.552	
С	0.36	0.61	0.014	0.024			L1	3.32	3.82	0.131	0.150	2
c1	0.36	0.56	0.014	0.022	4		ØΡ	3.54	3.91	0.139	0.154	
D	14.85	15.35	0.585	0.604	3		Q	2.60	3.00	0.102	0.118	
D1	8.38	9.02	0.330	0.355								

#### **Notes**

- <sup>(1)</sup> Dimensioning and tolerancing as per ASME Y14.5M-1994
- (2) Lead dimension and finish uncontrolled in L1
- (3) Dimension D, D1, and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body
- (4) Dimension b1, b3, and c1 apply to base metal only
- Controlling dimensions: inches
- (6) Thermal pad contour optional within dimensions E, H1, D2, and E1
- (7) Outline conforms to JEDEC® TO-220, except D2 (minimum)



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